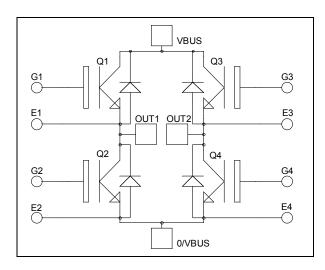
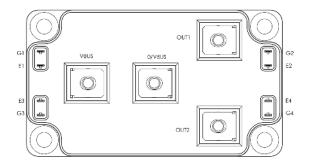


Full bridge High speed Trench + Field Stop IGBT4 Power module







Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- High speed Trench + Field Stop IGBT 4 Technology
 - Low voltage drop
 - Low leakage current
 - Low switching losses
 - Soft recovery parallel diodes
 - Low diode VF
 - RBSOA and SCSOA rated
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- **RoHS Compliant**

All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (Per IGBT)

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Voltage		1200	V
$I_{\rm C}$	Continuous Collector Current	$T_C = 25^{\circ}C$	350	
	Continuous Conector Current	$T_C = 80^{\circ}C$	200	A
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	700	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	1000	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	400A @ 1100V	

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



Electrical Characteristics (Per IGBT)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				100	μA
V	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		2.05	2.4	V
$V_{CE(sat)}$	Conector Emitter Saturation Voltage	$I_C = 200A$ $T_j = 150^{\circ}C$	$T_{j} = 150^{\circ}C$		2.6		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 7 \text{ mA}$		5.2	5.8	6.4	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				340	nA

Dynamic Characteristics (Per IGBT)

•	Characteristic	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			12.3		nF
C_{oes}	Output Capacitance				0.7		
C_{res}	Reverse Transfer Capacitance	f = 1MHz			0.6		
Q_G	Gate charge	V _{GE} = 15V ; V _{CE} =960V I _C =200A			900		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = \pm 15V$ $V_{CE} = 600V$ $I_{C} = 200A$ $R_{G} = 2.5\Omega$			30		ns
T _r	Rise Time				57		
$T_{d(off)}$	Turn-off Delay Time				290		
$T_{\rm f}$	Fall Time				16		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{CE} = 600V$ $I_{C} = 200A$ $R_{G} = 2.5\Omega$			30		ns
T_{r}	Rise Time				49		
T _{d(off)}	Turn-off Delay Time				366		
$T_{\rm f}$	Fall Time				48		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{CE} = 600V$	$T_{\rm J} = 150^{\circ}{\rm C}$		18		mJ
E _{off}	Turn-off Switching Energy	$I_C = 200A$ $R_G = 2.5\Omega$	$T_{\rm J} = 150^{\circ}{\rm C}$		11		mJ
I_{sc}	Short Circuit data	$V_{GE} \le 15V ; V_{Bus} = 600V$ $t_p \le 10 \mu s ; T_j = 150 ^{\circ} C$			700		A
R_{thJC}	Junction to Case Thermal Resistance					0.15	°C/W

Diode ratings and characteristics (Per diode)

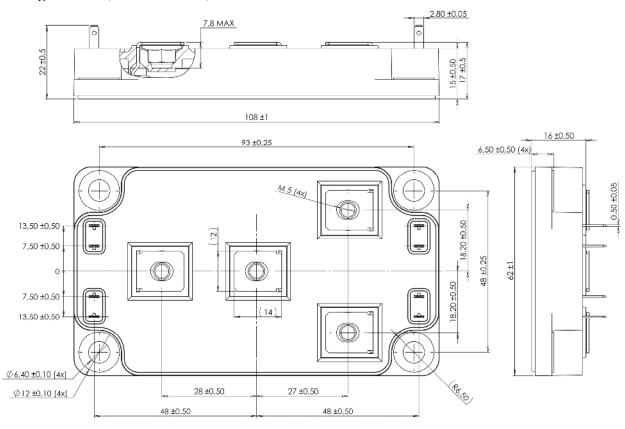
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Repetitive Reverse Voltage			1200			V
I_{RM}	Reverse Leakage Current	V _R =1200V				150	μΑ
I_F	DC Forward Current		$T_C = 60^{\circ}C$		200		Α
V	Diode Forward Voltage	$I_F = 200A$ $V_{GE} = 0V$	$T_j = 25^{\circ}C$		1.9	2.2	V
V_{F}			$T_{j} = 150^{\circ}C$		1.85		·
	D D T'		$T_j = 25$ °C		155		
t_{rr}	Reverse Recovery Time	1 2004	$T_{\rm j} = 150^{\circ}{\rm C}$		300		ns
0	Q_{rr} Reverse Recovery Charge $\begin{array}{c} I_F = 200A \\ V_R = 600V \\ di/dt = 4000A/\mu \end{array}$		$T_j = 25$ °C		18.6		C
Qrr		$di/dt = 4000A/\mu s$	$T_{j} = 150^{\circ}C$		39		μС
E_{r}	Reverse Recovery Energy		$T_j = 25^{\circ}C$		8		mJ
Ľr		$T_{\rm j} = 150^{\circ}$			16		1113
R_{thJC}	Junction to Case Thermal Resistance					0.25	°C/W



Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000		V
T_{J}	Operating junction temperature range			-40	175	°C
T _{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	
T_{STG}	Storage Temperature Range			-40	125	
$T_{\rm C}$	Operating Case Temperature			-40	100	
Torque	Mounting torque	To Heatsink	M6	3	5	N.m
Torque		For teminals	M5	2	3.5	18.111
Wt	Package Weight				300	gg

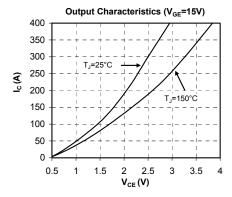
Package outline (dimensions in mm)

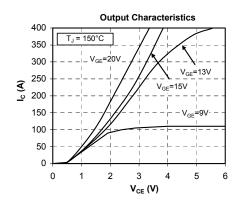


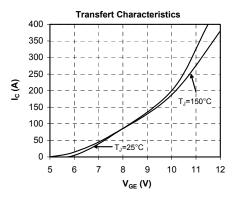
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

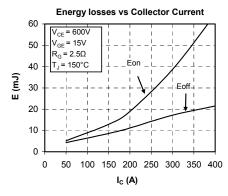


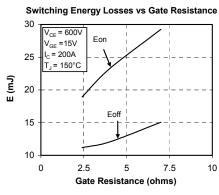
Typical Performance Curve

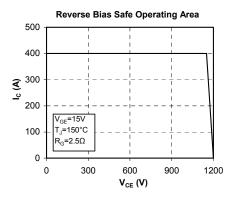


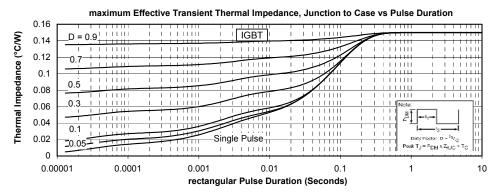




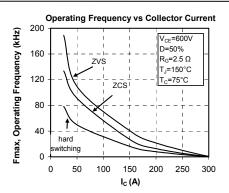


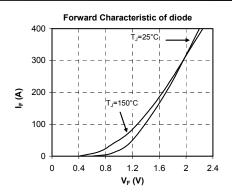


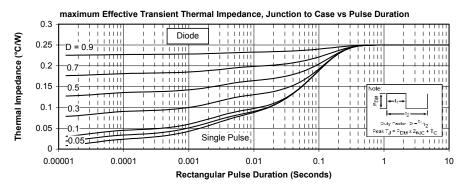














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